Specification

SOA0780016YY30DBXXXX

High-gain Semiconductor Optical Amplifier

Features:

- High gain (31dB) at 780nm
- High saturation output power (12dBm)
- Low ripples
- Strong linear polarization
- RoHS compliance
- · Proprietary anti-reflection coating technology enabling high reliability
- Polarization maintaining PM780 fiber or HI780 fiber
- 900um loose tube on fiber (optional)

Applications:

- Swept-source, tunable lasers
- Optical preamplifiers
- Optical coherence tomography (OCT)

Recommended Operating Conditions					
@ CW, the case is mounted on room temperature heatsink					
Parameter	Min.	Тур.	Max.	Unit	
Chip Temperature	20	25	30	°C	
Forward Current		300	400	mA	
Input Optical Power	-40	-25	10	dBm	

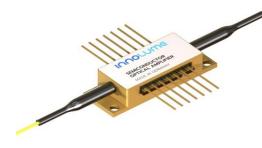
Gain Characteristics					
@ CW, 25°C, 300mA, with input signal -25dBm @ 780nm					
Parameter	Min.	Тур.	Max.	Unit	
Small Signal Gain @ 400mA	27	31		dB	
Saturation Output Power (-3dB) @ 400mA	9	12		dBm	
Wavelength of Gain Maximum	770	780	790	nm	
Gain Bandwidth (FWHM)	13	16		nm	
Noise Figure*		6.5		dB	

* - NF = 10log10(2p_ase/Ghv) [D.Baney et al., Optical Fiber Techn. 6, 122 (2000)]

Amplified Spontaneous Emission (ASE) Characteristics

@ CW, 25°C, 300mA, no input signal				
Parameter	Min.	Тур.	Max.	Unit
Output Power (each port)		20		mW
Forward Voltage		1.9	2.2	V
Mean Wavelength	770	780	790	nm
Bandwidth (FWHM)	11	14		nm
Ripples** (RMS)		0.01	0.2	dB
Polarisation Extinction Ratio (PER)	10	15		dB
Polarization		TE		

** - measured in 1nm span around spectrum maximum with 20pm resolution

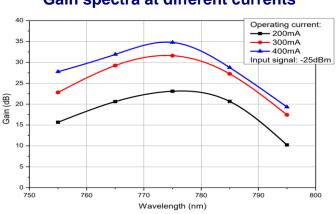


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Absolute Maximum Ratings					
Parameter	Min	Мах	Unit		
Output Optical Power		200	mW		
Input Optical Power		10	dBm		
Forward Current		400	mA		
Reverse Voltage		2	V		
TEC Current		3	А		
TEC Voltage		4	V		
Chip Operating Temperature	10	40	°C		
Case Operating Temperature	0	70	°C		
Storage Temperature	-40	85	°C		
Pin Soldering Temperature (max 10 sec, max case temperature 120°C)		300	°C		
Fiber Band Radius	3		cm		

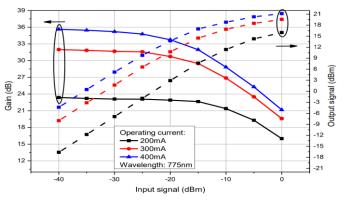
Typical Performance (for reference only)

@ CW, the case is mounted on room temperature heatsink



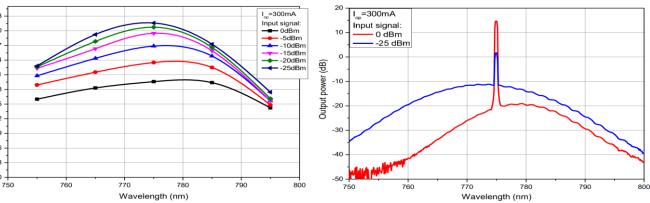
Gain spectra at different currents

Gain and Output power vs. Input signal



Gain spectra at different input signals

Spectra of amplified optical signal



33

30

27

24

21

12

9 6

3 0 -

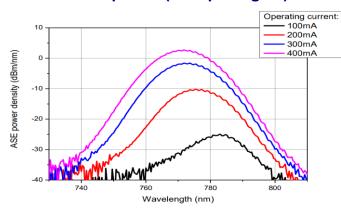
Gain (dB) 18 15

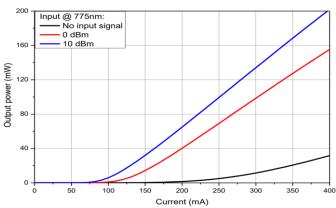
Specification

ASE Spectra (no input signal)

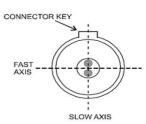
INNOLUME







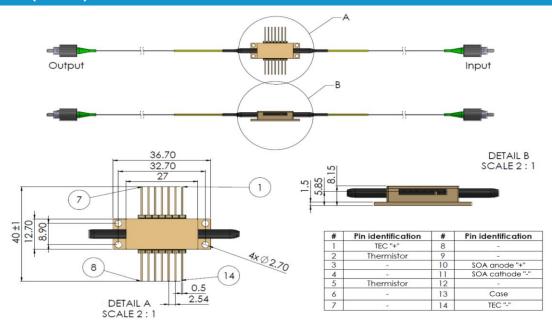
Thermistor spec	ification		Fiber specification			
Parameters	Value	Unit	Parameters	Value	Value	Unit
Туре	NTC		Fiber Type	HI780	PM780	
Resistance @ 25°C	10±0.1	kOhm	Numerical Aperture (Typical)	0.14	0.12	
Beta 25-85°C	3435±1%	К	Cut-off Wavelength	720±50	710±60	nm
	Mode-Field Diameter	4.6±0.5 @ 780nm	4.6±0.5 @780nm	μm		
25000 20000			Cladding Diameter	125±1	125±1	μm
+			Coating Diameter	245±15	245±15	μm
15000 498124 4981			Loose Tube Diameter (optional)	900	900	μm
5000			Connector	FC/APC	FC/APC	
	20 25 40 45 5	50 55 60	Кеу	narrow	narrow	
	nperature, C	0 00 00				



The output light is polarized along the slow axis of PM fiber.

Specification

Dimensions (in mm)



Safety and Operating Instructions

The light emitted from this device is invisible and can be harmful to the human eye. Avoid looking directly into the fiber connector when the device is in operation. Proper laser safety eyewear must be worn during operation with open connector. Absolute Maximum Ratings may be applied to the device for short period of time only. Exposure to maximum ratings for extended period of time or exposure to more than one maximum rating may cause damage or affect the reliability of the device. Operating the device outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum forward current cannot be exceeded.

A proper heatsink for the device on thermal radiator is required. The device must be mounted on radiator with 4 screws (bolt down in X-style fashion with initial torque set to 0.075Nm and final X-style bolt down at 0.15Nm) or with clamps. The deviation from flatness of radiator surface must be less than 0.05mm. It's recommended using of Indium foil or thermal conductive and soft material between bottom of the case and heatsink for thermal interface. It's undesirable to use thermal grease for this. Avoid back reflection to the device. It may give impact on the device performance in aspects of spectrum and power stability. It also may cause fatal facet damage. Using of optical isolators is highly recommended to block back reflection. Do not pull the fiber. Do not bend a fiber with a radius smaller than 3 cm. Fiber tip should always be protected from any contamination or damage during the process of installation. After removing the dust-preventing cap covered at fiber tip, carefully clean fiber tip by wiping through one direction using optical lens cleaning paper or cotton swab dabbed with Iso-Propanol or Ethyl alcohol. Operate the device with clean fiber connector only.

ESD PROTECTION - Electrostatic discharge is the primary cause of unexpected product failure. Take extreme precaution to prevent ESD. During device installation, ESD protection has to be maintained - use wrist straps, grounded work surfaces and rigorous antistatic techniques when handling the product.





Specification

Part-number Identification

SOA0780016HI40DBXXXX -> 40dB gain at 780nm gain maximum and 16nm gain bandwidth, HI-1060 fiber SOA0780016PM40DBLXXX -> 40dB gain at 780nm gain maximum and 16nm gain bandwidth, PM-980 fiber, with loose tube

NOTE: Innolume product specifications are subject to change without notice